

SILICON POWER TRANSISTOR 2SA1744

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

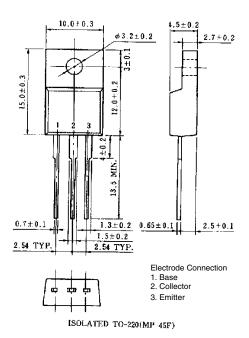
The 2SA1744 is a power transistor developed for high-speed switching and features a high here at Low VcE(sat). This transistor is ideal for use as a driver in DC/DC converters and actuators.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

FEATURES

- High hre and low VcE(sat): hre ≥ 100 (VcE = -2 V, Ic = -3 A) $VcE(sat) \leq 0.3$ V (Ic = -8 A, IB = -0.4 A)
- Full-mold package that does not require an insulating board or bushing

PACKAGE DRAWING (UNIT: mm)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vcво	-100	٧
Collector to emitter voltage	VCEO	-60	٧
Emitter to base voltage	VEBO	-7.0	٧
Collector current (DC)	Ic(DC)	-15	Α
Collector current (pulse)	Ic(pulse)*	-30	Α
Base current (DC)	I _{B(DC)}	-7.5	Α
Total power dissipation	P _T (Tc = 25°C)	30	W
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

^{*} PW \leq 300 μ s, duty cycle \leq 10%

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ELECTRICAL CHARACTERISTICS (TA = 25°C)

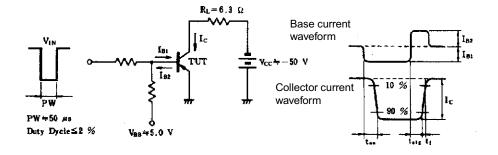
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = -8.0 A, I _B = -0.8 A, L = 1 mH	-60			٧
Collector to emitter voltage	VCEX(SUS)	$I_{C} = -8.0 \text{ A}, I_{B1} = -I_{B2} = -0.8 \text{ A},$ $V_{BE(OFF)} = 1.5 \text{ V}, L = 180 \ \mu\text{H}, clamped}$				V
Collector cutoff current	Ісво	Vcb = -60 V, IE = 0			-10	μΑ
Collector cutoff current	ICER	VCE = -60 V, RBE = 50 Ω , TA = 125° C			-1.0	mA
Collector cutoff current	ICEX1	Vce = -60 V, Vbe(OFF) = 1.5 V			-10	μΑ
Collector cutoff current	ICEX2	$V_{CE} = -60 \text{ V}, V_{BE(OFF)} = 1.5 \text{ V},$ $T_A = 125^{\circ}C$			-1.0	mA
Emitter cutoff current	ІЕВО	V _{EB} = -5.0 V, I _C = 0			-10	μΑ
DC current gain	h _{FE1} *	VcE = -2.0 V, Ic = -1.5 A	100			
DC current gain	h _{FE2} *	VcE = -2.0 V, Ic = -3.0 A	100		400	
DC current gain	h _{FE3} *	Vce = -2.0 V, Ic = -8.0 A	60			
Collector saturation voltage	V _{CE(sat)1} *	Ic = -8.0 A, I _B = -0.4 A			-0.3	٧
Collector saturation voltage	V _{CE(sat)2} *	Ic = -12 A, I _B = -0.6 A			-0.5	٧
Base saturation voltage	V _{BE(sat)1} *	Ic = -8.0 A, I _B = -0.4 A			-1.2	٧
Base saturation voltage	V _{BE(sat)2} *	Ic = -12 A, I _B = -0.6 A			-1.5	٧
Collector capacitance	Сор	V _{CB} = −10 V, I _E = 0, f = 1.0 MHz		300		pF
Gain bandwidth product	f⊤	VcE = −10 V, Ic = −1.5 A		80		MHz
Turn-on time	ton	$Ic = -8.0 \text{ A}, R_L = 6.3 \Omega,$			0.3	μs
Storage time	tstg	$I_{B1} = -I_{B2} = -0.4 \text{ A}, \text{ Vcc } \cong -50 \text{ V}$ Refer to the test circuit.			1.5	μs
Fall time	t _f	neier to the test circuit.			0.3	μs

^{*} Pulse test PW \leq 350 μ s, duty cycle \leq 2%

hfe CLASSIFICATION

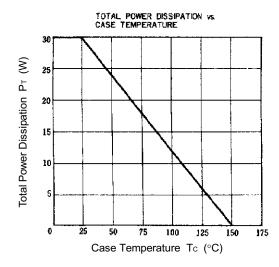
Marking	М	L	K
h _{FE2}	100 to 200	150 to 300	200 to 400

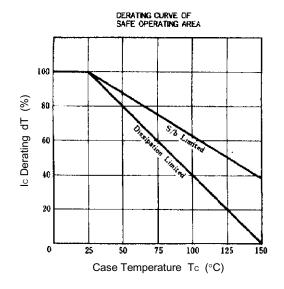
SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

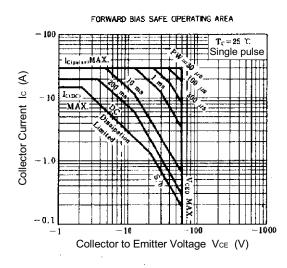


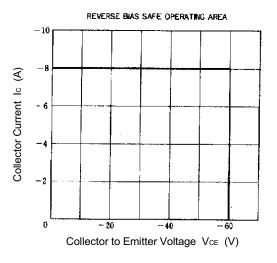


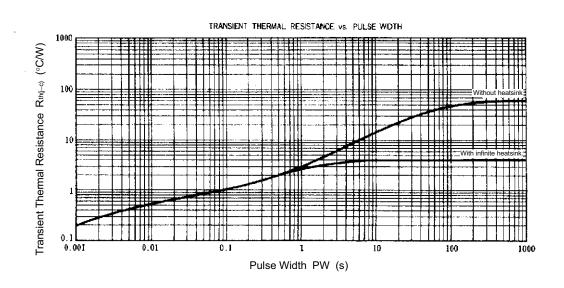
TYPICAL CHARACTERISTICS (TA = 25°C)



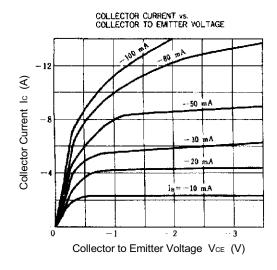


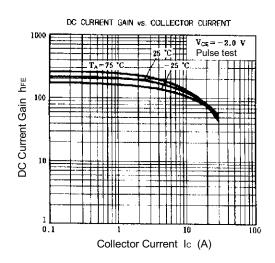


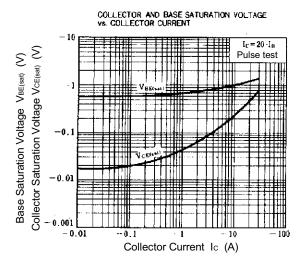


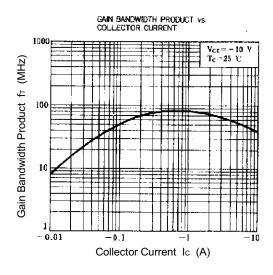


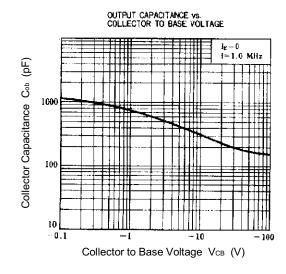
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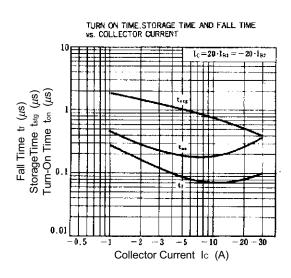














[MEMO]

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